NSN 5961-01-060-9657

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-060-9657 **Inclosure Material:** Metal **Overall Length:** 0.475 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, peak **Current Rating Per Characteristic:** 25.00 amperes drain current universal **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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